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[ZXTP19020DGTA](#)

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A Product Line of
Diodes Incorporated



ZXTP19020DG

20V PNP HIGH GAIN TRANSISTOR IN SOT223

Features

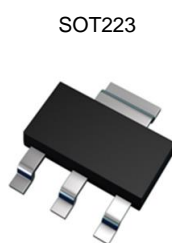
- $BV_{CEO} > -20V$
- $BV_{ECO} > -4V$
- $I_C = 8A$ High Continuous Current
- Low Saturation Voltage $V_{CE(sat)} < -47mV @ 1A$
- $R_{CE(sat)} = 28m\Omega$
- Complementary PNP Type: ZXTN19020DG
- **Lead-Free Finish; RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**

Mechanical Data

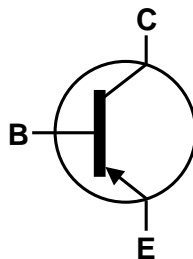
- Case: SOT223
- Case Material: Molded Plastic, "Green" Molding Compound;
- UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish - Matte Tin Plated Leads; Solderable per MIL-STD-202, Method 208 ③
- Weight: 0.112 grams (Approximate)

Applications

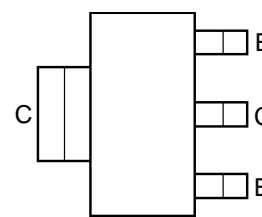
- Motor Drive
- Relay, Lamp and Solenoid Drive



Top View



Device Symbol



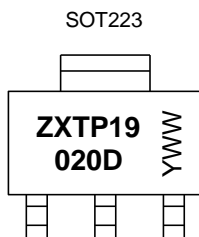
Top View
Pin-Out

Ordering Information (Note 4)

Product	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZXTP19020DGTA	AEC-Q101	ZXTP19020D	7	12	1,000

- Notes:
1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 4. For packaging details, go to our website at <http://www.diodes.com/products/packages.html>.

Marking Information



ZXTP19020D = Product Type Marking Code
 YWW = Date Code Marking
 Y or \bar{Y} = Last Digit of Year (ex: 5= 2015)
 WW or $\bar{W}W$ = Week Code (01-53)

Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-25	V
Collector-Emitter Voltage	V _{CEO}	-20	V
Emitter-Collector Voltage (reverse blocking)	V _{ECO}	-4	V
Emitter-Base Voltage	V _{EBO}	-7	V
Continuous Collector Current	I _C	-8	A
Base Current	I _B	-1	A
Peak Pulse Current	I _{CM}	-15	A

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

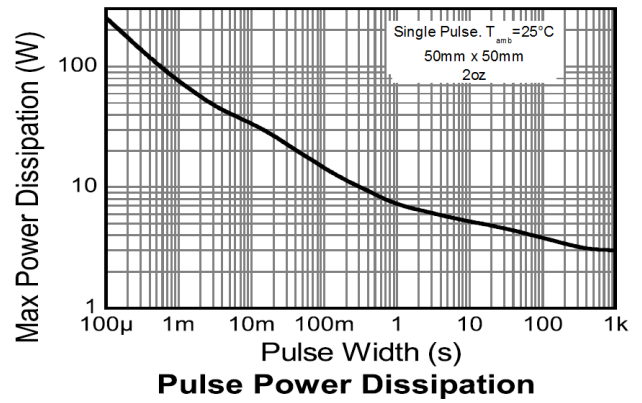
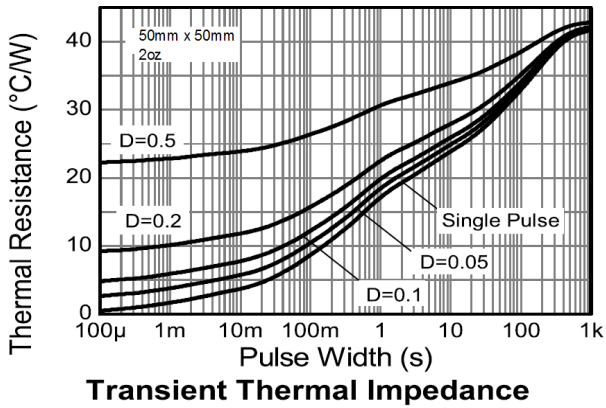
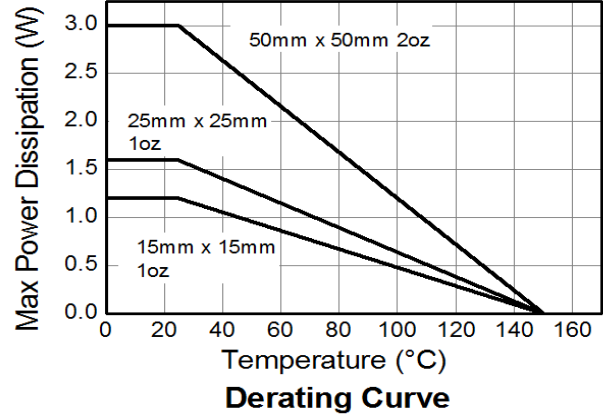
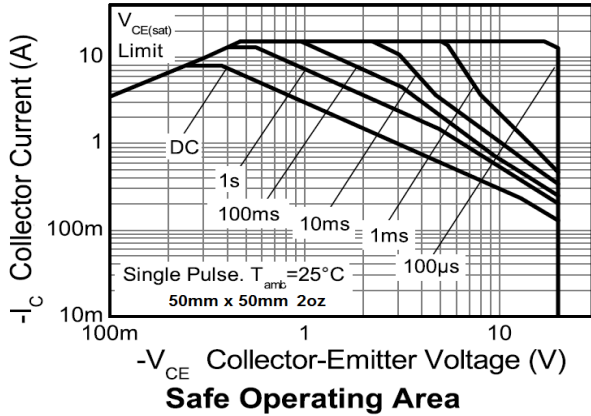
Characteristic	Symbol	Value	Unit
Power Dissipation Linear Derating Factor	P _D	1.2	W mW/°C
		9.6	
		1.6	
		12.8	
		3	
Thermal Resistance, Junction to Ambient	R _{θJA}	24	°C/W
		5.3	
		42	
		104	
Thermal Resistance, Junction to Lead	R _{θJL}	78	°C/W
		42	
		23.5	
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

ESD Ratings (Note 10)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	C

- Notes:
- For a device mounted with the collector lead on 15mm x 15mm 1oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in steady-state.
 - Same as Note 6, except the device is mounted on 25mm x 25mm 1oz copper.
 - Same as Note 6, except the device is mounted on 50mm x 50mm 2oz copper.
 - Same as Note 8 measured at t<5 seconds.
 - Thermal resistance from junction to solder-point (at the end of the collector lead).
 - Refer to JEDEC specification JESD22-A114 and JESD22-A115.

Thermal Characteristics and Derating Information (@T_A = +25°C, unless otherwise specified.)

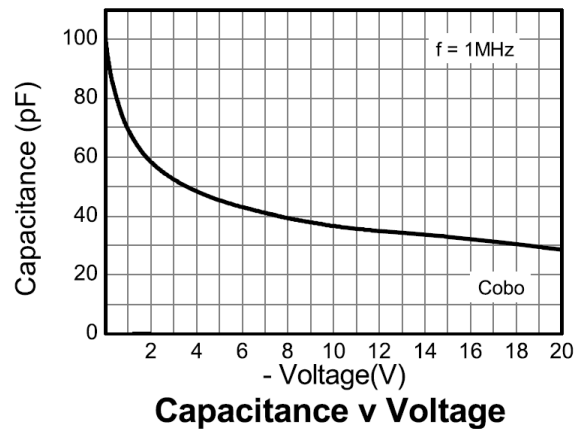
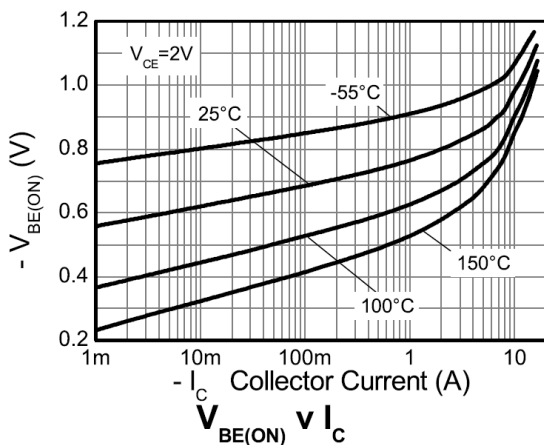
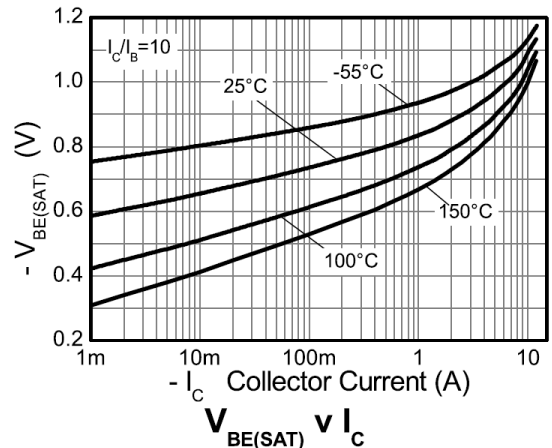
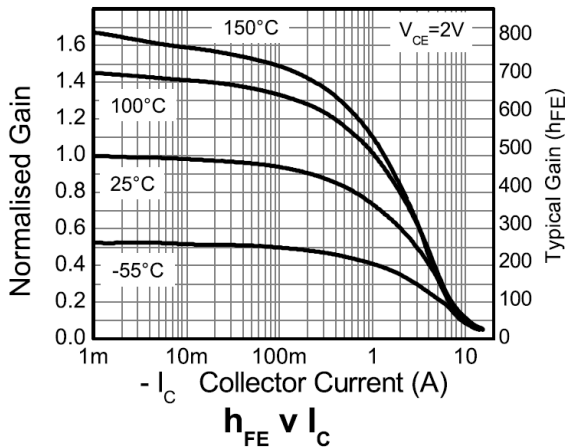
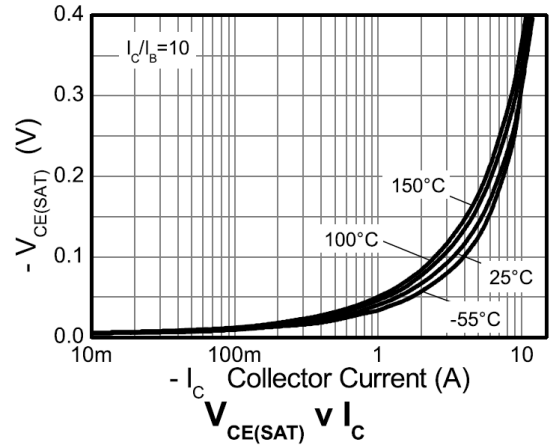
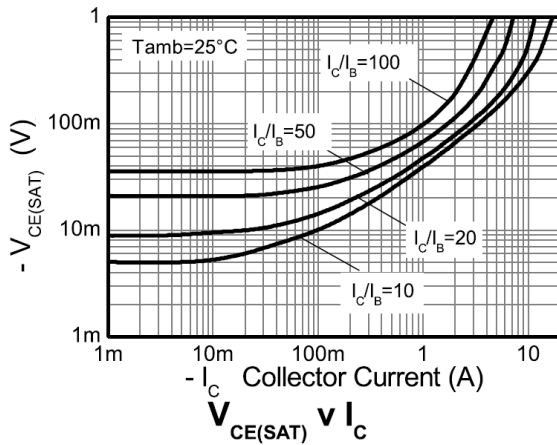


Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CB0}	-25	-55	-	V	I _C = -100μA
Collector-Emitter Breakdown Voltage (Note 11)	BV _{CEO}	-20	-50	-	V	I _C = -10mA
Emitter-Collector Breakdown Voltage (reverse blocking)	BV _{ECX}	-4	-8.6	-	V	I _C = -100μA, R _{BC} < 1kΩ or 0.25V < V _{BC} > -0.25V
Emitter-Collector Breakdown Voltage (reverse blocking)	BV _{ECO}	-4	-8.6	-	V	I _E = -100μA
Emitter-Base Breakdown Voltage	BV _{EBO}	-7	-8.2	-	V	I _E = -100μA
Collector Cut-Off Current	I _{CB0}	-	< 1	-50	nA	V _{CB} = -25V
		-	-	-0.5	μA	V _{CB} = -25V, T _A = +100°C
Emitter Cut-Off Current	I _{EBO}	-	< 1	-50	nA	V _{EB} = -5.6V
Collector-Emitter Saturation Voltage (Note 11)	V _{CE(sat)}	-	-40	-47	mV	I _C = -1A, I _B = -100mA
		-	-97	-130	mV	I _C = -1A, I _B = -10mA
		-	-115	-145	mV	I _C = -2A, I _B = -40mA
		-	-220	-275	mV	I _C = -8A, I _B = -800mA
Base-Emitter Saturation Voltage (Note 11)	V _{BE(sat)}	-	-1050	-1150	mV	I _C = -8A, I _B = -800mA
Base-Emitter Turn-On Voltage (Note 11)	V _{BE(on)}	-	-930	-1000	mV	I _C = -8A, V _{CE} = -2V
DC Current Gain (Note 11)	h _{FE}	300	450	900	-	I _C = -100mA, V _{CE} = -2V
		200	290	-	-	I _C = -2A, V _{CE} = -2V
		45	70	-	-	I _C = -8A, V _{CE} = -2V
		-	25	-	-	I _C = -15A, V _{CE} = -2V
Current Gain-Bandwidth Product (Note 11)	f _T	-	176	-	MHz	V _{CE} = -10V, I _C = -50mA, f = 50MHz
Input Capacitance (Note 11)	C _{ibo}	-	-	400	pF	V _{EB} = -0.5V, f = 1MHz
Output Capacitance (Note 11)	C _{obo}	-	36	45	pF	V _{CB} = -10V, f = 1MHz
Delay Time	t _d	-	23	-	ns	I _C = -1A, V _{CC} = -10V, I _{B1} = -I _{B2} = -50mA
Rise Time	t _r	-	18.4	-	ns	
Storage Time	t _s	-	266	-	ns	
Fall Time	t _f	-	49.6	-	ns	

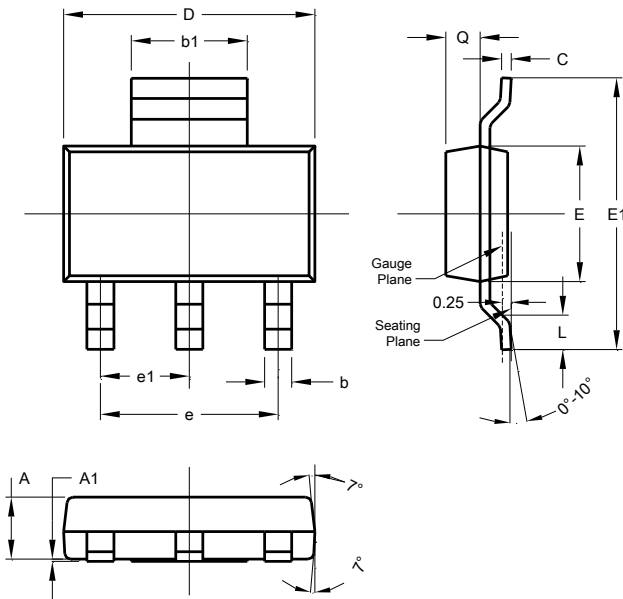
Note: 11. Measured under pulsed conditions. Pulse width ≤ 300μs. Duty cycle ≤ 2%.

Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)



Package Outline Dimensions

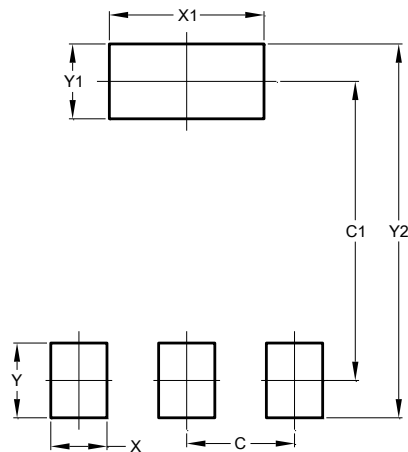
Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for the latest version.



SOT223			
Dim	Min	Max	Typ
A	1.55	1.65	1.60
A1	0.010	0.15	0.05
b	0.60	0.80	0.70
b1	2.90	3.10	3.00
C	0.20	0.30	0.25
D	6.45	6.55	6.50
E	3.45	3.55	3.50
E1	6.90	7.10	7.00
e	-	-	4.60
e1	-	-	2.30
L	0.85	1.05	0.95
Q	0.84	0.94	0.89
All Dimensions in mm			

Suggested Pad Layout

Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for the latest version.



Dimensions	Value (in mm)
C	2.30
C1	6.40
X	1.20
X1	3.30
Y	1.60
Y1	1.60
Y2	8.00

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